

H11D1X, H11D2X, H11D3X, H11D4X  
H11D1, H11D2, H11D3, H11D4



**ISOCOM**  
COMPONENTS

**HIGH VOLTAGE OPTICALLY  
COUPLED ISOLATOR  
PHOTOTRANSISTOR OUTPUT**



**'X' SPECIFICATION APPROVALS**

- VDE0884 in 3 available lead forms :-  
- STD  
- G form  
- SMD approved to CECC 00802

**DESCRIPTION**

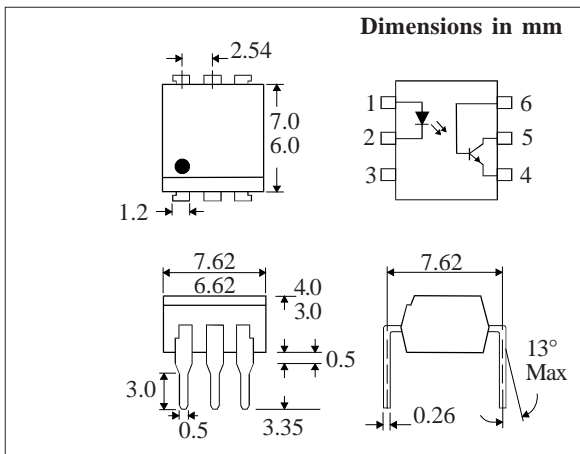
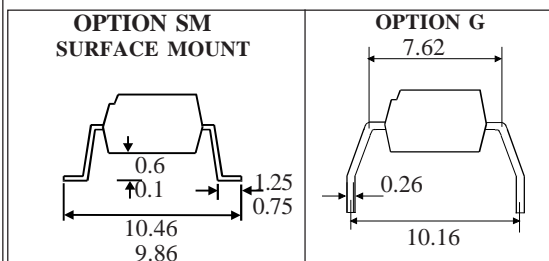
The H11D series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

**FEATURES**

- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- High BV<sub>CER</sub> ( 300V - H11D1, H11D2 )  
( 200V - H11D3, H11D4 )
- All electrical parameters 100% tested
- Custom electrical selections available

**APPLICATIONS**

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS**  
(25°C unless otherwise specified)

Storage Temperature \_\_\_\_\_ -55°C to + 150°C  
Operating Temperature \_\_\_\_\_ -55°C to + 100°C  
Lead Soldering Temperature  
(1/16 inch (1.6mm) from case for 10 secs) 260°C

**INPUT DIODE**

Forward Current \_\_\_\_\_ 60mA  
Reverse Voltage \_\_\_\_\_ 6V  
Power Dissipation \_\_\_\_\_ 100mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage BV<sub>CER</sub> (R<sub>BE</sub> = 1MΩ)  
H11D1, H11D2 \_\_\_\_\_ 300V  
H11D3, H11D4 \_\_\_\_\_ 200V  
Collector-base Voltage BV<sub>CBO</sub>  
H11D1, H11D2 \_\_\_\_\_ 300V  
H11D3, H11D4 \_\_\_\_\_ 200V  
Emitter-collector Voltage BV<sub>ECO</sub> \_\_\_\_\_ 6V  
Collector Current \_\_\_\_\_ 100mA  
Power Dissipation \_\_\_\_\_ 150mW

**POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 250mW  
(derate linearly 2.67mW/°C above 25°C)

**ISOCOM COMPONENTS 2004 LTD**

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**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

| PARAMETER                      |   | MIN                | TYP | MAX           | UNITS            | TEST CONDITION   |
|--------------------------------|---|--------------------|-----|---------------|------------------|--|
| Input                          | Forward Voltage ( $V_F$ )   |                    | 1.2 | 1.5           | V                | $I_F = 10\text{mA}$  |
|                                | Reverse Current ( $I_R$ )   |                    |     | 10            | $\mu\text{A}$    | $V_R = 6\text{V}$  |
| Output                         | Collector-emitter Breakdown ( $BV_{\text{CER}}$ )<br>H11D1, H11D2   | 300                |     |               | V                | $I_C = 1\text{mA}, R_{\text{BE}} = 1\text{M}\Omega$<br>( note 2 )  |
|                                | H11D3, H11D4  | 200                |     |               | V                |  |
|                                | Collector-base Breakdown ( $BV_{\text{CBO}}$ )<br>H11D1, H11D2      | 300                |     |               | V                | $I_C = 100\mu\text{A}$   |
|                                | H11D3, H11D4  | 200                |     |               | V                |  |
|                                | Emitter-collector Breakdown ( $BV_{\text{ECO}}$ )                   | 6                  |     |               | V                | $I_E = 100\mu\text{A}$   |
|                                | Collector-emitter Dark Current ( $I_{\text{CER}}$ )<br>H11D1, H11D2 |                    |     | 100           | nA               | $V_{\text{CE}} = 200\text{V}, R_{\text{BE}} = 1\text{M}\Omega$<br>$V_{\text{CE}} = 200\text{V}, R_{\text{BE}} = 1\text{M}\Omega,$<br>$T_A = 100^\circ\text{C}$ |
| H11D3, H11D4                   |   |                    | 250 | $\mu\text{A}$ |                  |  |
| Coupled                        | Current Transfer Ratio (CTR)  | 20                 |     |               | %                | $10\text{mA } I_F, 10\text{V } V_{\text{CE}},$<br>$R_{\text{BE}} = 1\text{M}\Omega$  |
|                                | Collector-emitter Saturation Voltage $V_{\text{CE(SAT)}}$           |                    |     | 0.4           | V                |  |
|                                | Input to Output Isolation Voltage $V_{\text{ISO}}$                  | 5300               |     |               | $V_{\text{RMS}}$ | See note 1   |
|                                |   | 7500               |     |               | $V_{\text{PK}}$  |  |
|                                | Input-output Isolation Resistance $R_{\text{ISO}}$                  | $5 \times 10^{10}$ |     |               | $\Omega$         | $V_{\text{IO}} = 500\text{V}$ (note 1)   |
|                                | Turn-on Time $t_{\text{on}}$  |                    | 5   |               | $\mu\text{s}$    | $V_{\text{CC}} = 10\text{V}, I_C = 2\text{mA},$<br>$R_L = 100\Omega$ , fig 1   |
| Turn-off Time $t_{\text{off}}$ |   | 5                  |     | $\mu\text{s}$ |                  |  |

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

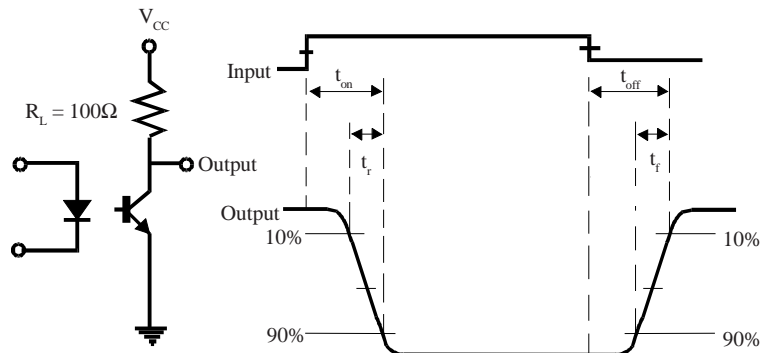
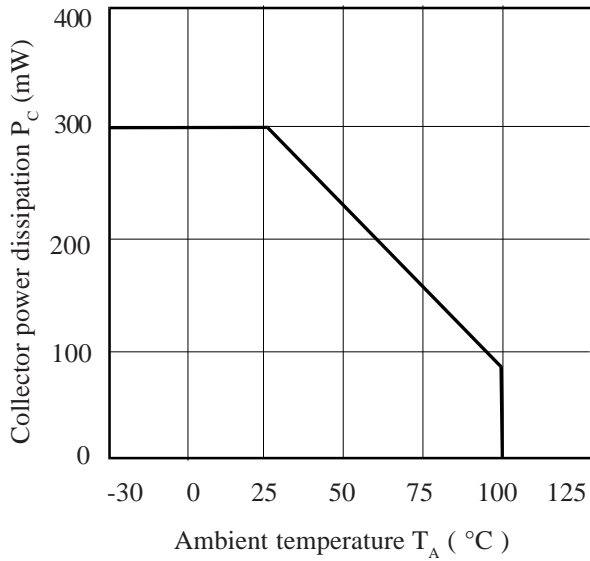
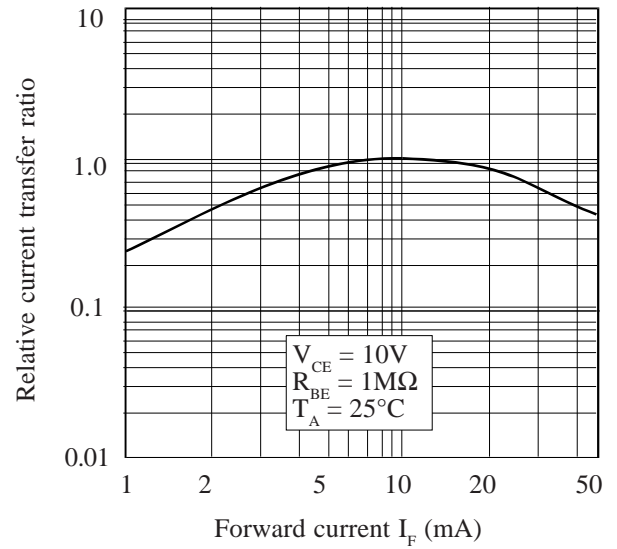


FIG 1

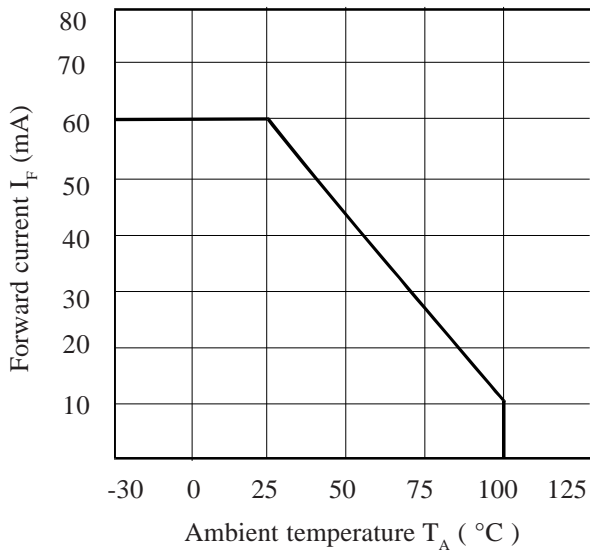
**Collector Power Dissipation vs. Ambient Temperature**



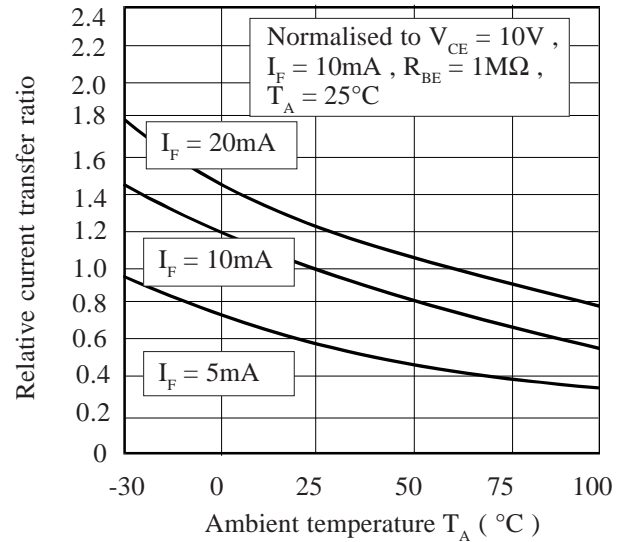
**Relative Current Transfer Ratio vs. Forward Current (normalised to 10mA  $I_F$ )**



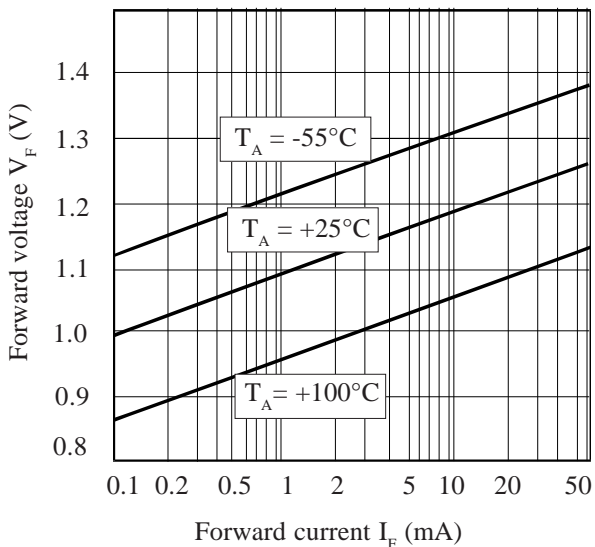
**Forward Current vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Ambient Temperature**



**Forward Voltage vs. Forward Current**



**Collector-base Current vs. Ambient Temperature**

